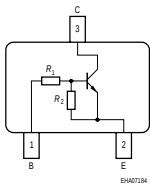


NPN Silicon Digital Transistor

- Switching circuit, inverter, interface circuit, driver circuit
- Built in bias resistor ($R_1=22k\Omega$, $R_2=47k\Omega$)


BCR142/F/L3
BCR142T/W


Type	Marking	Pin Configuration						Package
BCR142	WZs	1=B	2=E	3=C	-	-	-	SOT23
BCR142F	WZs	1=B	2=E	3=C	-	-	-	TSFP-3
BCR142FL3	WZ	1=B	2=E	3=C	-	-	-	TSLP-3-4
BCR142T	WZs	1=B	2=E	3=C	-	-	-	SC75
BCR142W	WZs	1=B	2=E	3=C	-	-	-	SOT323

Maximum Ratings

Parameter	Symbol	Value	Unit
Collector-emitter voltage	V_{CEO}	50	V
Collector-base voltage	V_{CBO}	50	
Emitter-base voltage	V_{EBO}	10	
Input on voltage	$V_{i(on)}$	30	
Collector current	I_C	100	mA
Total power dissipation- BCR142, $T_S \leq 102^\circ\text{C}$ BCR142F, $T_S \leq 128^\circ\text{C}$ BCR142L3, $T_S \leq 135^\circ\text{C}$ BCR142T, $T_S \leq 109^\circ\text{C}$ BCR142W, $T_S \leq 124^\circ\text{C}$	P_{tot}	200 250 250 250 250	mW
Junction temperature	T_j	150	
Storage temperature	T_{stg}	-65 ... 150	

Thermal Resistance

Parameter	Symbol	Value	Unit
Junction - soldering point ¹⁾ BCR142 BCR142F BCR142L3 BCR142T BCR142W	R_{thJS}	≤ 240 ≤ 90 ≤ 60 ≤ 165 ≤ 105	K/W

¹⁾For calculation of R_{thJA} please refer to Application Note Thermal Resistance

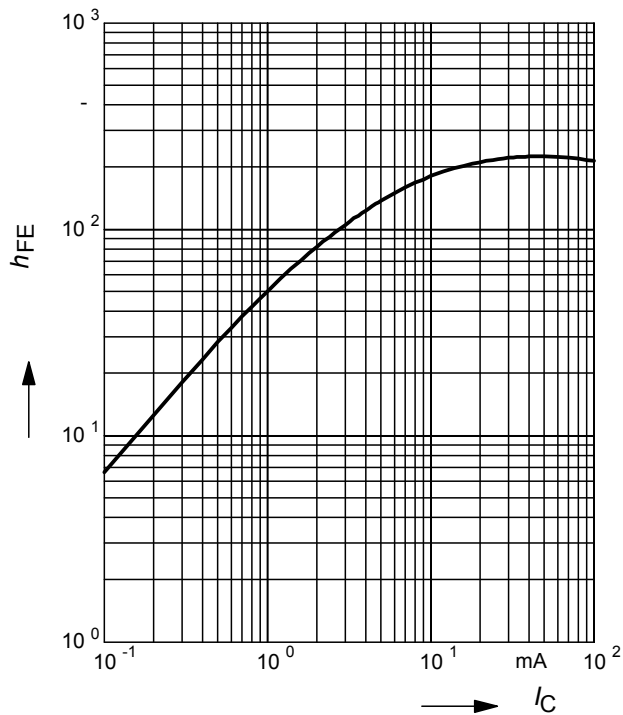
Electrical Characteristics at $T_A = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics					
Collector-emitter breakdown voltage $I_C = 100\ \mu\text{A}$, $I_B = 0$	$V_{(\text{BR})\text{CEO}}$	50	-	-	V
Collector-base breakdown voltage $I_C = 10\ \mu\text{A}$, $I_E = 0$	$V_{(\text{BR})\text{CBO}}$	50	-	-	
Collector-base cutoff current $V_{\text{CB}} = 40\ \text{V}$, $I_E = 0$	I_{CBO}	-	-	100	nA
Emitter-base cutoff current $V_{\text{EB}} = 10\ \text{V}$, $I_C = 0$	I_{EBO}	-	-	227	μA
DC current gain-1) $I_C = 5\ \text{mA}$, $V_{\text{CE}} = 5\ \text{V}$	h_{FE}	70	-	-	-
Collector-emitter saturation voltage1) $I_C = 10\ \text{mA}$, $I_B = 0.5\ \text{mA}$	V_{CEsat}	-	-	0.3	V
Input off voltage $I_C = 100\ \mu\text{A}$, $V_{\text{CE}} = 5\ \text{V}$	$V_{\text{i(off)}}$	0.5	-	1.2	
Input on voltage $I_C = 2\ \text{mA}$, $V_{\text{CE}} = 0.3\ \text{V}$	$V_{\text{i(on)}}$	0.8	-	2.5	
Input resistor	R_1	15	22	29	k Ω
Resistor ratio	R_1/R_2	0.42	0.47	0.52	-
AC Characteristics					
Transition frequency $I_C = 10\ \text{mA}$, $V_{\text{CE}} = 5\ \text{V}$, $f = 100\ \text{MHz}$	f_{T}	-	150	-	MHz
Collector-base capacitance $V_{\text{CB}} = 10\ \text{V}$, $f = 1\ \text{MHz}$	C_{cb}	-	3	-	pF

¹⁾Pulse test: $t < 300\ \mu\text{s}$; $D < 2\%$

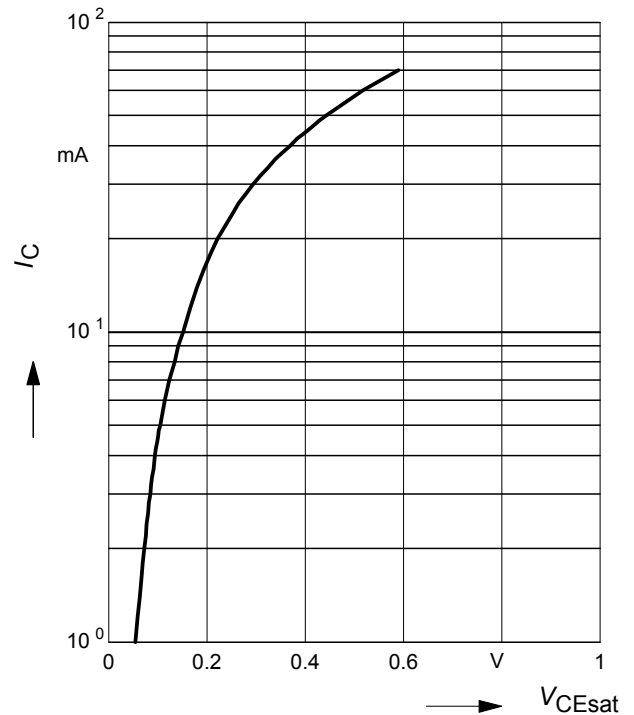
DC current gain $h_{FE} = f(I_C)$

$V_{CE} = 5V$ (common emitter configuration)



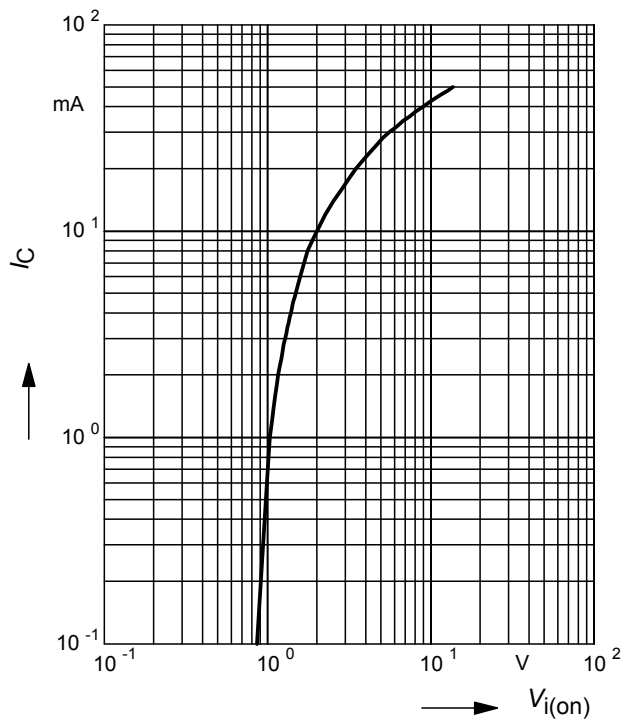
Collector-emitter saturation voltage

$V_{CEsat} = f(I_C), h_{FE} = 20$



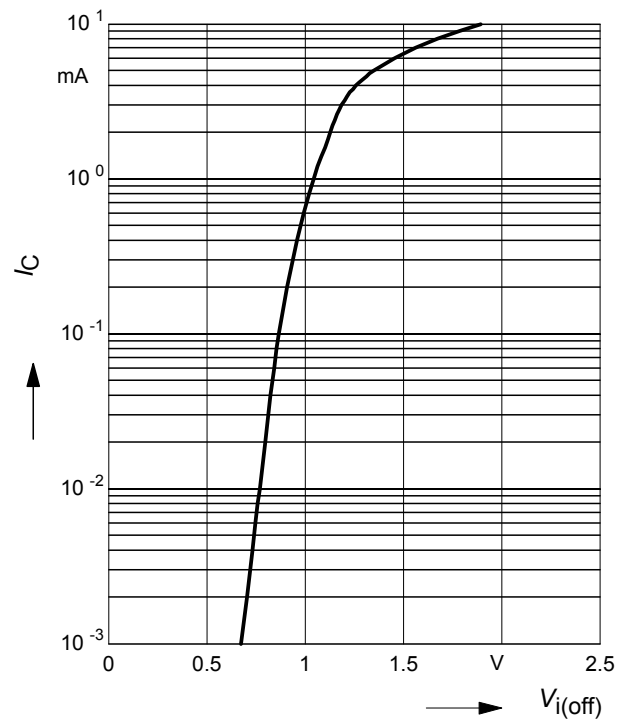
Input on Voltage $V_{i(on)} = f(I_C)$

$V_{CE} = 0.3V$ (common emitter configuration)



Input off voltage $V_{i(off)} = f(I_C)$

$V_{CE} = 5V$ (common emitter configuration)



Total power dissipation $P_{\text{tot}} = f(T_S)$

BCR142



Total power dissipation $P_{\text{tot}} = f(T_S)$

BCR142F



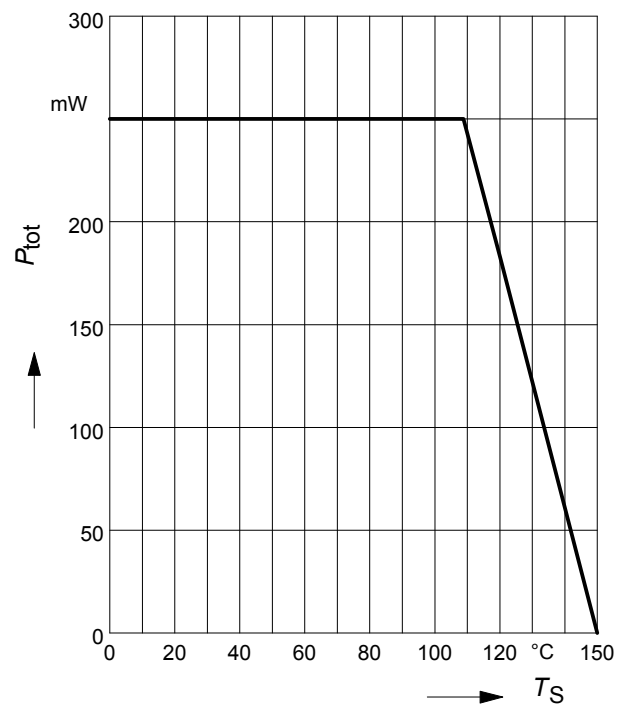
Total power dissipation $P_{\text{tot}} = f(T_S)$

BCR142L3



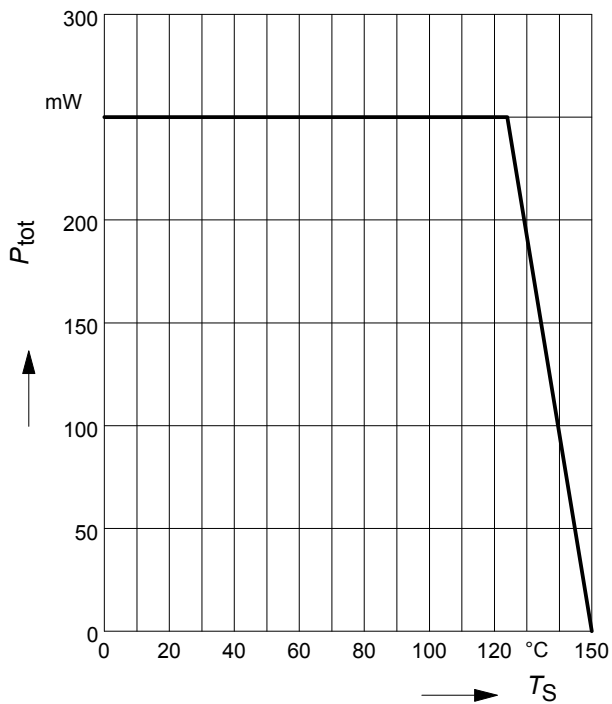
Total power dissipation $P_{\text{tot}} = f(T_S)$

BCR142T



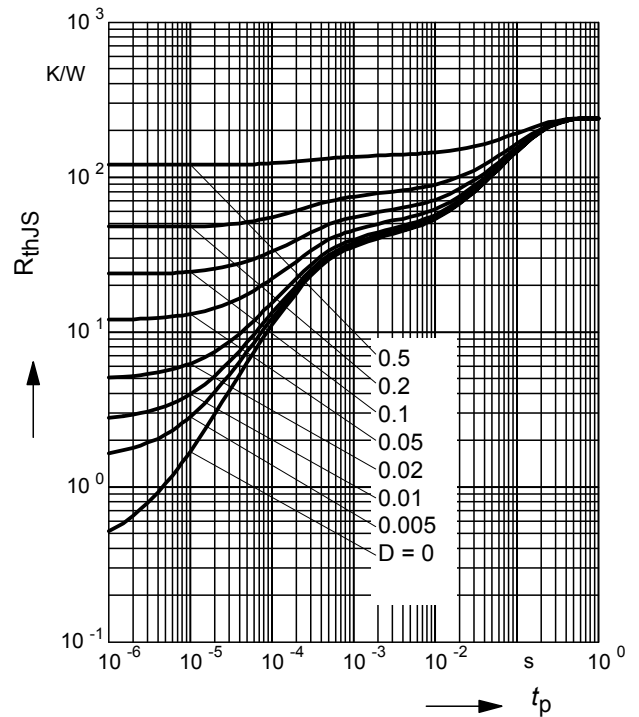
Total power dissipation $P_{\text{tot}} = f(T_S)$

BCR142W



Permissible Pulse Load $R_{\text{thJS}} = f(t_p)$

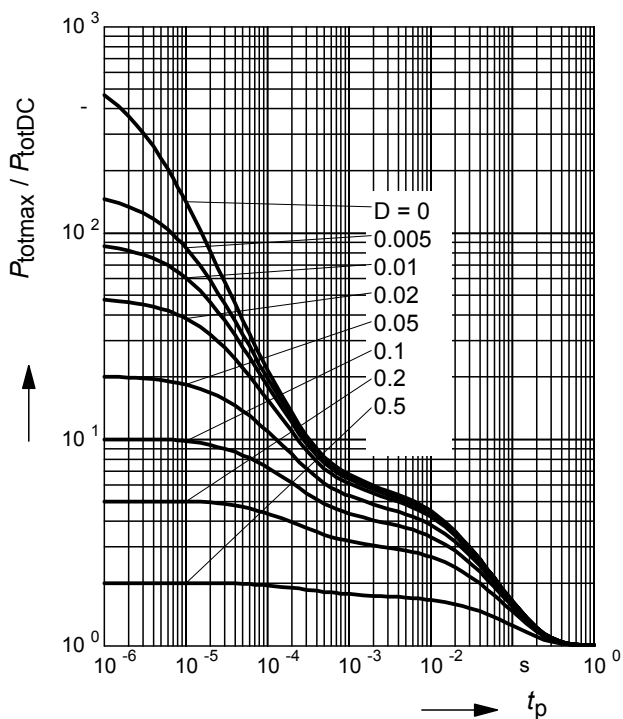
BCR142



Permissible Pulse Load

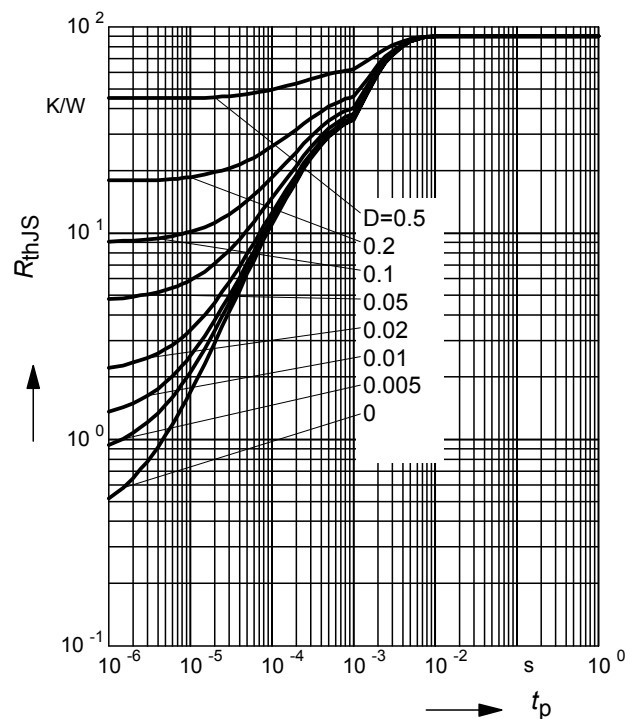
$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$

BCR142



Permissible Puls Load $R_{\text{thJS}} = f(t_p)$

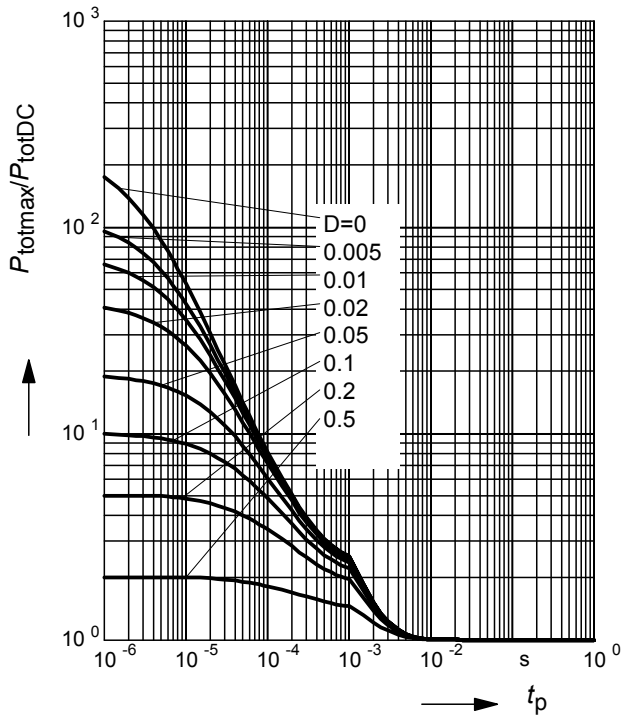
BCR142F



Permissible Pulse Load

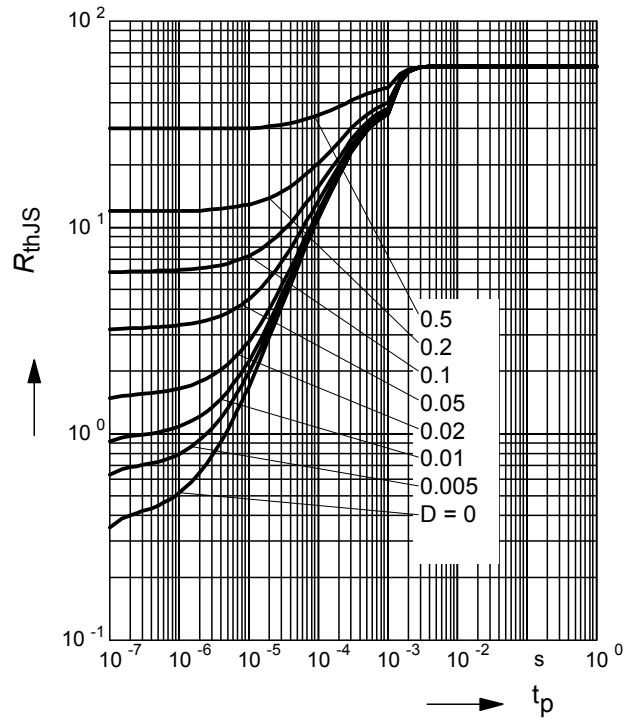
$$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$$

BCR142F



Permissible Puls Load $R_{\text{thJS}} = f(t_p)$

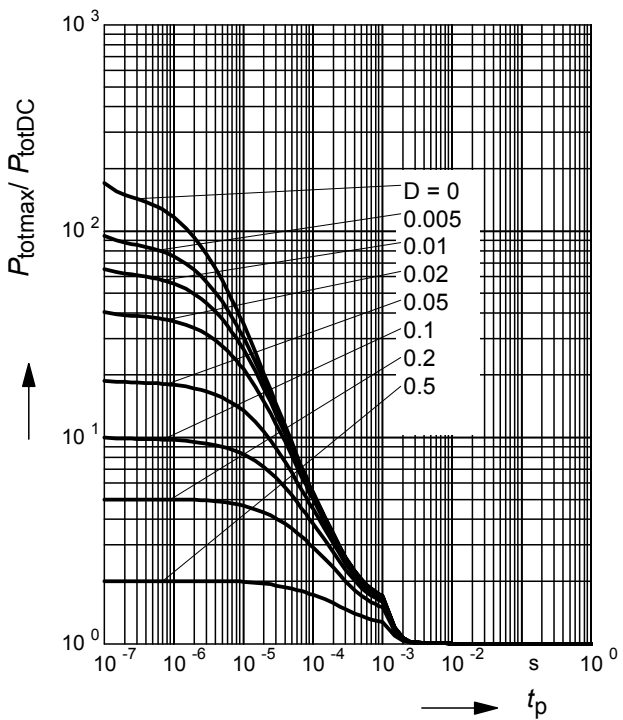
BCR142L3



Permissible Pulse Load

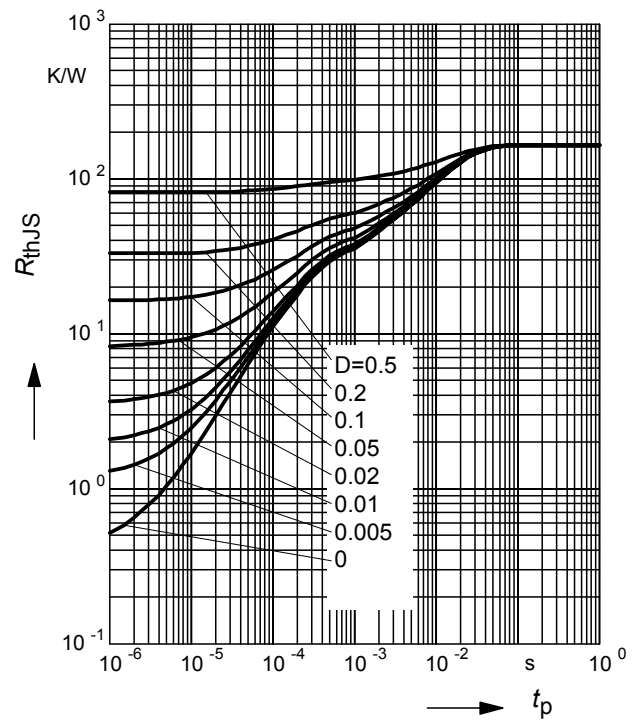
$$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$$

BCR142L3



Permissible Puls Load $R_{\text{thJS}} = f(t_p)$

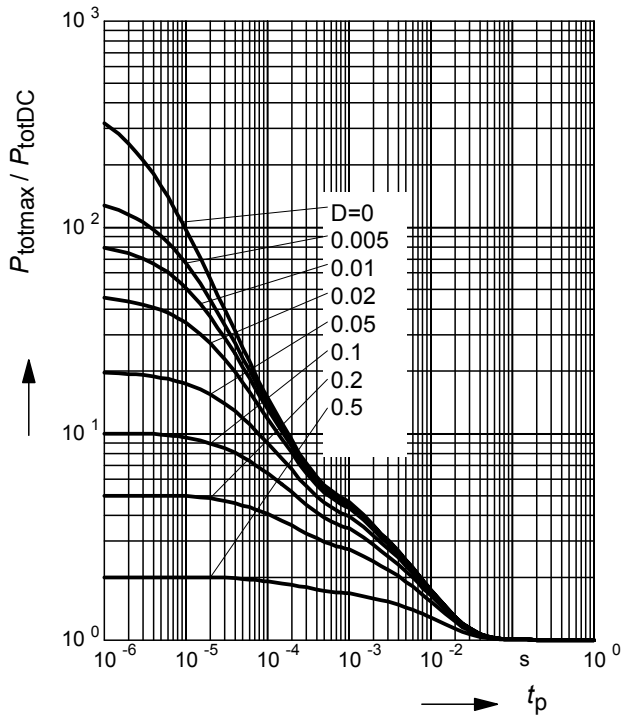
BCR142T



Permissible Pulse Load

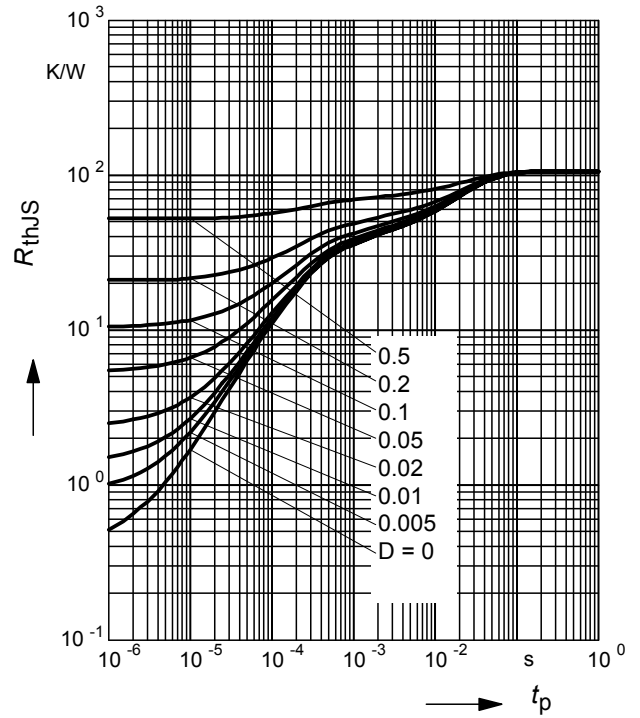
$$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$$

BCR142T



Permissible Puls Load $R_{\text{thJS}} = f(t_p)$

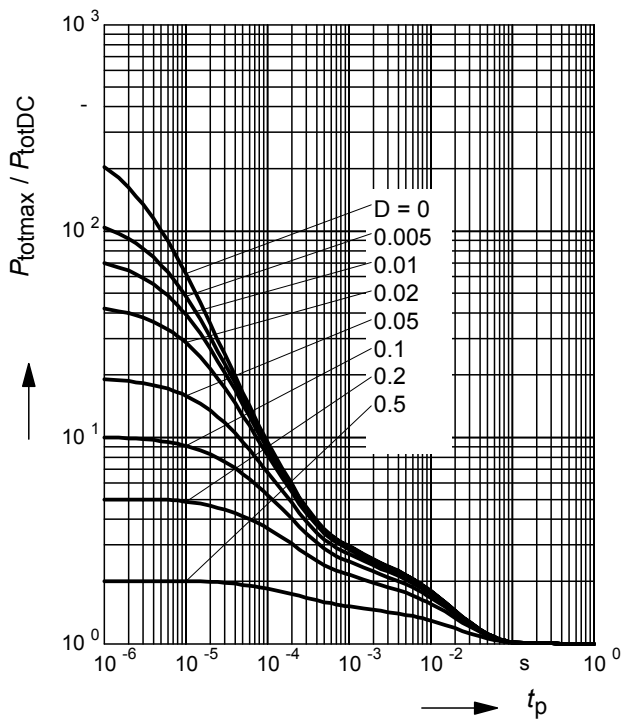
BCR142W



Permissible Pulse Load

$$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$$

BCR142W



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